

# DATA SHEET

**TDA6109JF**

Triple video output amplifier

Preliminary specification  
File under Integrated Circuits, IC02

2001 Jul 04

# Triple video output amplifier

# TDA6109JF

**FEATURES**

- Typical bandwidth of 9.0 MHz for an output signal of 60 V (p-p)
- High slew rate of 1850 V/ $\mu$ s
- No external components required
- Very simple application
- Single supply voltage of 200 V
- Internal reference voltage of 2.5 V
- Fixed gain of 51

- Black-Current Stabilization (BCS) circuit
- Thermal protection.

**GENERAL DESCRIPTION**

The TDA6109JF includes three video output amplifiers in one plastic DIL-bent-SIL 9-pin medium power (DBS9MPF) package (SOT111-1), using high-voltage DMOS technology, and is intended to drive the three cathodes of a colour CRT directly. To obtain maximum performance, the amplifier should be used with black-current control.

**ORDERING INFORMATION**

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TDA6109JF	DBS9MPF	plastic DIL-bent-SIL medium power package with fin; 9 leads	SOT111-1

**BLOCK DIAGRAM**

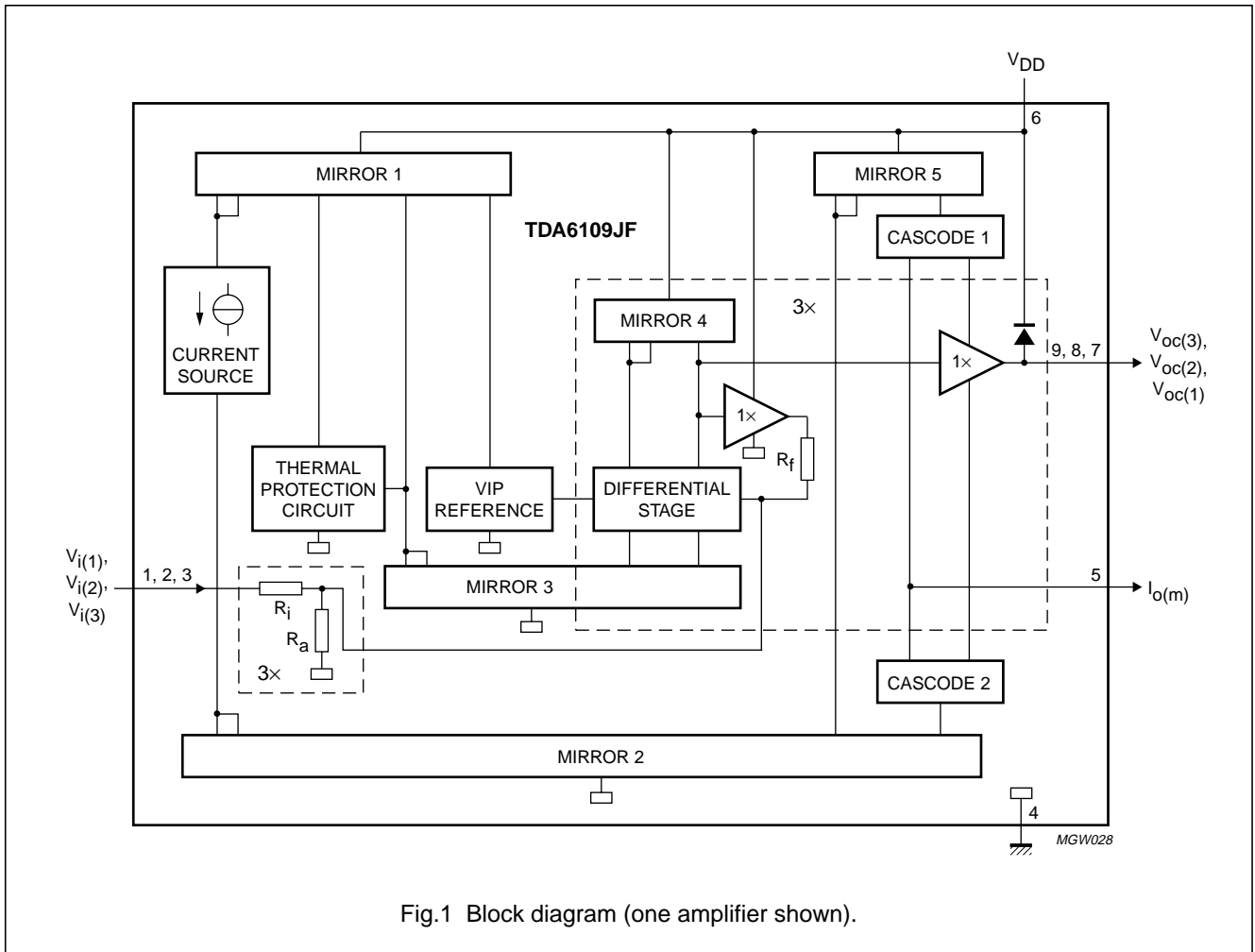


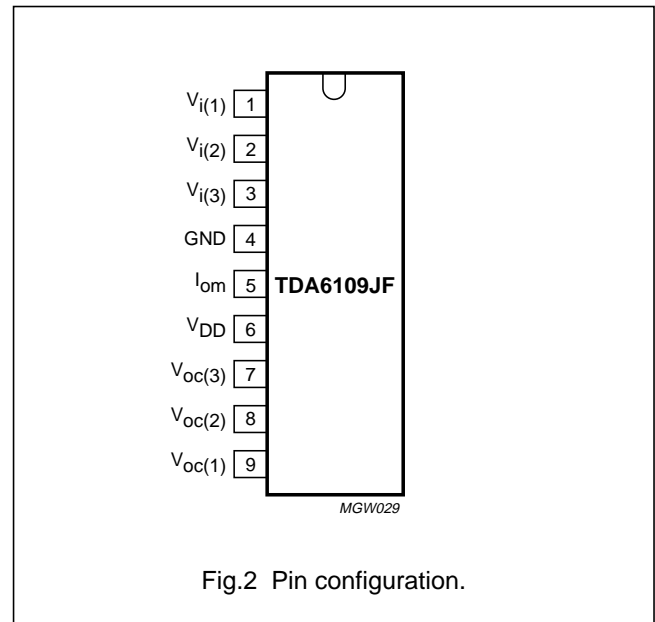
Fig.1 Block diagram (one amplifier shown).

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## PINNING

SYMBOL	PIN	DESCRIPTION
$V_{i(1)}$	1	inverting input 1
$V_{i(2)}$	2	inverting input 2
$V_{i(3)}$	3	inverting input 3
GND	4	ground (fin)
$I_{om}$	5	black current measurement output
$V_{DD}$	6	supply voltage
$V_{oc(3)}$	7	cathode output 3
$V_{oc(2)}$	8	cathode output 2
$V_{oc(1)}$	9	cathode output 1



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages measured with respect to pin 4 (ground); currents as specified in Fig.1; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{DD}$	supply voltage		0	250	V
$V_i$	input voltage		0	12	V
$V_{om}$	measurement output voltage		0	6	V
$V_{oc}$	cathode output voltage		0	$V_{DD}$	V
$ I_{om(\text{mean})} $	absolute value of mean current of measurement output (for three channels)	$1.5 \text{ V} < V_i < 5.5 \text{ V};$ $3 \text{ V} < V_{om} < 6 \text{ V}$	–	5	mA
$T_{\text{stg}}$	storage temperature		–55	+150	°C
$T_j$	junction temperature		–20	+150	°C
$V_{\text{es}}$	electrostatic handling				
	human body model (HBM)		–	2000	V
	machine model (MM)		–	300	V

## HANDLING

Inputs and outputs are protected against electrostatic discharge in normal handling. However, to be totally safe, it is desirable to take normal precautions appropriate to handling MOS devices.

## QUALITY SPECIFICATION

Quality specification “SNW-FQ-611D” is applicable.

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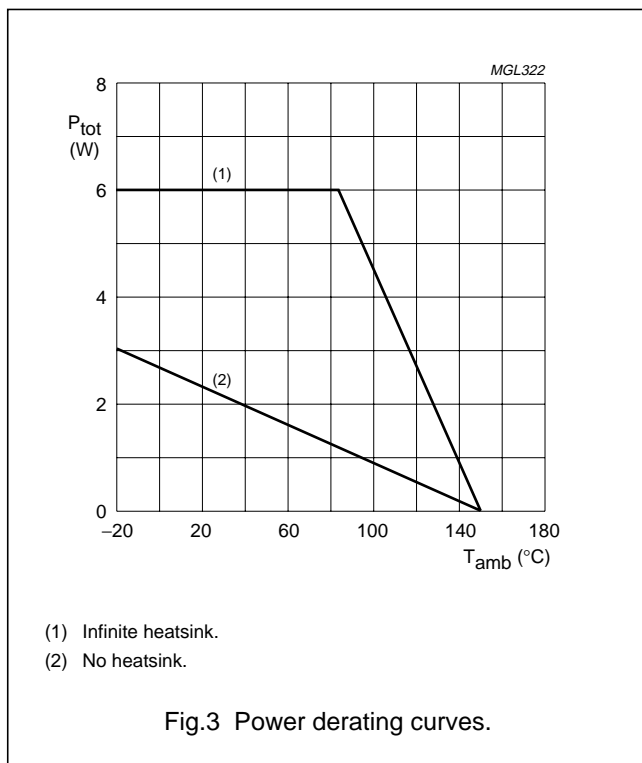
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**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient		56	K/W
$R_{th(j-fin)}$	thermal resistance from junction to fin	note 1	11	K/W
$R_{th(h-a)}$	thermal resistance from heatsink to ambient		10	K/W

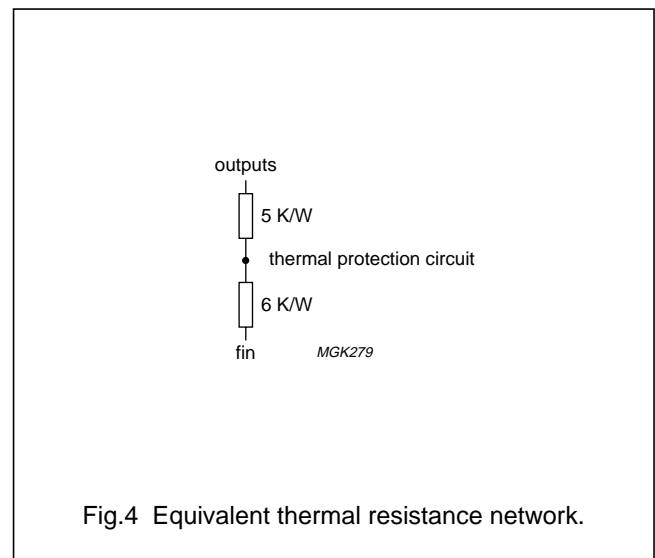
**Note**

1. An external heatsink is necessary.



**Thermal protection**

The internal thermal protection circuit gives a decrease of the slew rate at high temperatures: 10% decrease at 130 °C and 30% decrease at 145 °C (typical values on the spot of the thermal protection circuit).



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**CHARACTERISTICS**

Operating range:  $T_j = -20$  to  $+150$  °C;  $V_{DD} = 180$  to  $210$  V. Test conditions:  $T_{amb} = 25$  °C;  $V_{DD} = 200$  V;

$V_{oc(1)} = V_{oc(2)} = V_{oc(3)} = \frac{1}{2}V_{DD}$ ;  $C_L = 10$  pF ( $C_L$  consists of parasitic and cathode capacitance);  $R_{th(h-a)} = 10$  K/W (measured in test circuit of Fig.8); unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_q$	quiescent supply current		8.8	10.3	11.7	mA
$V_{ref(int)}$	internal reference voltage (input stage)		–	2.5	–	V
$R_i$	input resistance		–	3.2	–	k $\Omega$
G	gain of amplifier		47.5	51.0	55.0	
$\Delta G$	gain difference		–2.5	0	+2.5	
$V_{oc}$	nominal output voltage at pins 7, 8 and 9 (DC value)	$I_i = 0$	116	129	142	V
$\Delta V_{oc(offset)}$	differential nominal output offset voltage between pins 7 and 8, 8 and 9 and 9 and 7 (DC value)	$I_i = 0$	–	0	5	V
$\Delta V_{oc(T)}$	output voltage temperature drift at pins 7, 8 and 9		–	–10	–	mV/K
$\Delta V_{oc(offset)(T)}$	differential output offset voltage temperature drift between pins 7 and 8, 8 and 9 and 7 and 9		–	0	–	mV/K
$I_{om(offset)}$	offset current of measurement output (for three channels)	$I_{oc} = 0$ ; $1.5$ V < $V_i$ < $5.5$ V; $3$ V < $V_{om}$ < $6$ V	–50	–	+50	$\mu$ A
$\Delta I_{om}/\Delta I_{oc}$	linearity of current transfer (for three channels)	$-100$ $\mu$ A < $I_{oc}$ < $100$ $\mu$ A; $1.5$ V < $V_i$ < $5.5$ V; $3$ V < $V_{om}$ < $6$ V	0.9	1.0	1.1	
		$-100$ $\mu$ A < $I_{oc}$ < $18$ mA; $1.5$ V < $V_i$ < $5.5$ V; $3$ V < $V_{om}$ < $4$ V	0.9	1.0	1.1	
$I_{oc(max)}$	maximum peak output current (pins 7, 8 and 9)	$50$ V < $V_{oc}$ < $V_{DD} - 50$ V	–	28	–	mA
$V_{oc(min)}$	minimum output voltage (pins 7, 8 and 9)	$V_i = 7.0$ V; note 1	–	–	10	V
$V_{oc(max)}$	maximum output voltage (pins 7, 8 and 9)	$V_i = 1.0$ V; note 1	$V_{DD} - 15$	–	–	V
$B_S$	small signal bandwidth (pins 7, 8 and 9)	$V_{oc} = 60$ V (p-p)	–	9.0	–	MHz
$B_L$	large signal bandwidth (pins 7, 8 and 9)	$V_{oc} = 100$ V (p-p)	–	8.0	–	MHz
$t_{Poc}$	cathode output propagation time 50% input to 50% output (pins 7, 8 and 9)	$V_{oc} = 100$ V (p-p) square wave; $f < 1$ MHz; $t_r = t_f = 40$ ns (pins 1, 2 and 3); see Figs 6 and 7	–	32	–	ns
$\Delta t_{Poc}$	difference in cathode output propagation time 50% input to 50% output (pins 7 and 8, 7 and 9 and 8 and 9)	$V_{oc} = 100$ V (p-p) square wave; $f < 1$ MHz; $t_r = t_f = 40$ ns (pins 1, 2 and 3)	–10	0	+10	ns

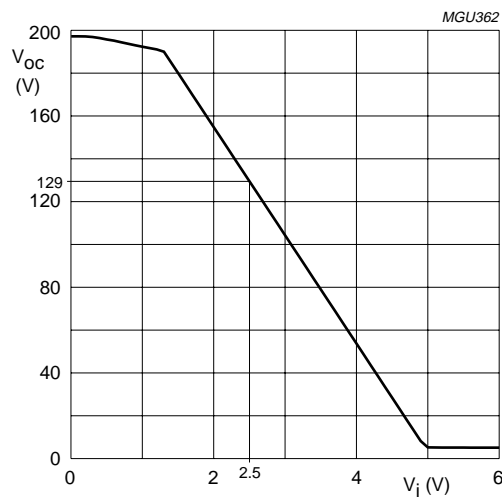
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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$t_{r(oc)}$	cathode output rise time 10% output to 90% output (pins 7, 8 and 9)	$V_{oc} = 50$ to $150$ V square wave; $f < 1$ MHz; $t_r = 40$ ns (pins 1, 2 and 3); see Fig.6	35	50	65	ns
$t_{f(oc)}$	cathode output fall time 90% output to 10% output (pins 7, 8 and 9)	$V_{oc} = 150$ to $50$ V square wave; $f < 1$ MHz; $t_f = 40$ ns (pins 1, 2 and 3); see Fig.7	35	50	65	ns
$t_{st}$	settling time 50% input to 99% < output < 101% (pins 7, 8 and 9)	$V_{oc} = 100$ V (p-p) square wave; $f < 1$ MHz; $t_r = t_f = 40$ ns (pins 1, 2 and 3); see Figs 6 and 7	–	–	350	ns
SR	slew rate between 50 V to ( $V_{DD} - 50$ V) (pins 7, 8 and 9)	$V_i = 4$ V (p-p) square wave; $f < 1$ MHz; $t_r = t_f = 40$ ns (pins 1, 2 and 3)	–	1850	–	V/ $\mu$ s
$V_{oc(overshoot)}$	cathode output voltage overshoot (pins 7, 8 and 9)	$V_{oc} = 100$ V (p-p) square wave; $f < 1$ MHz; $t_r = t_f = 40$ ns (pins 1, 2 and 3); see Figs 6 and 7	–	10	–	%
PSRR	power supply rejection ratio	$f < 50$ kHz; note 2	–	65	–	dB
$\alpha_{ct(DC)}$	DC crosstalk between channels		–	–50	–	dB

**Notes**

- See also Fig.5 for the typical DC-to-DC transfer of  $V_i$  to  $V_{oc}$ .
- The ratio of the change in supply voltage to the change in input voltage when there is no change in output voltage.

Fig.5 Typical DC-to-DC transfer of  $V_i$  to  $V_{oc}$ .

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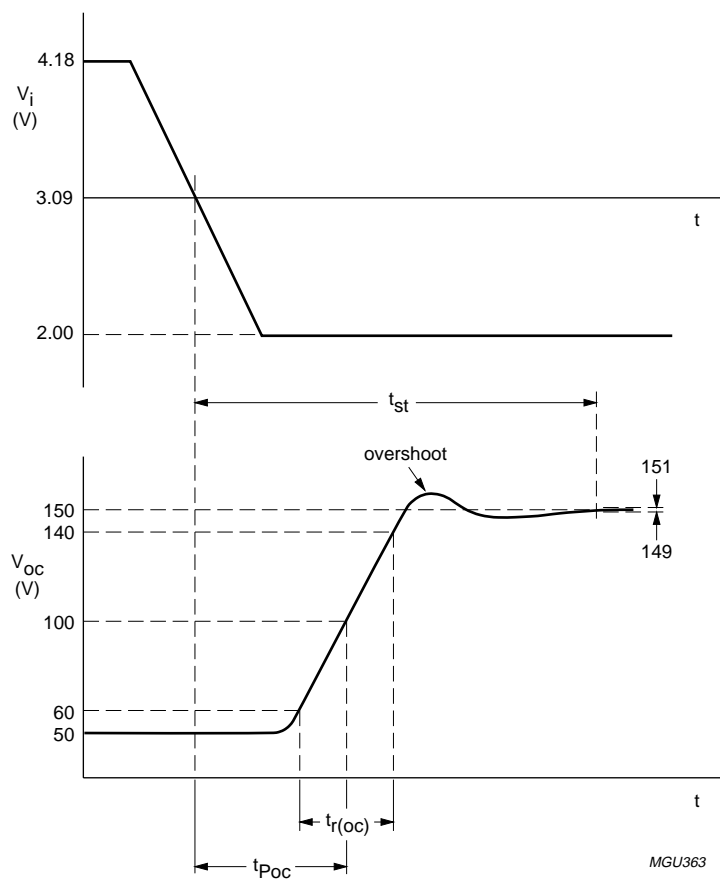


Fig.6 Output voltage (pins 7, 8 and 9) rising edge as a function of the AC input signal.

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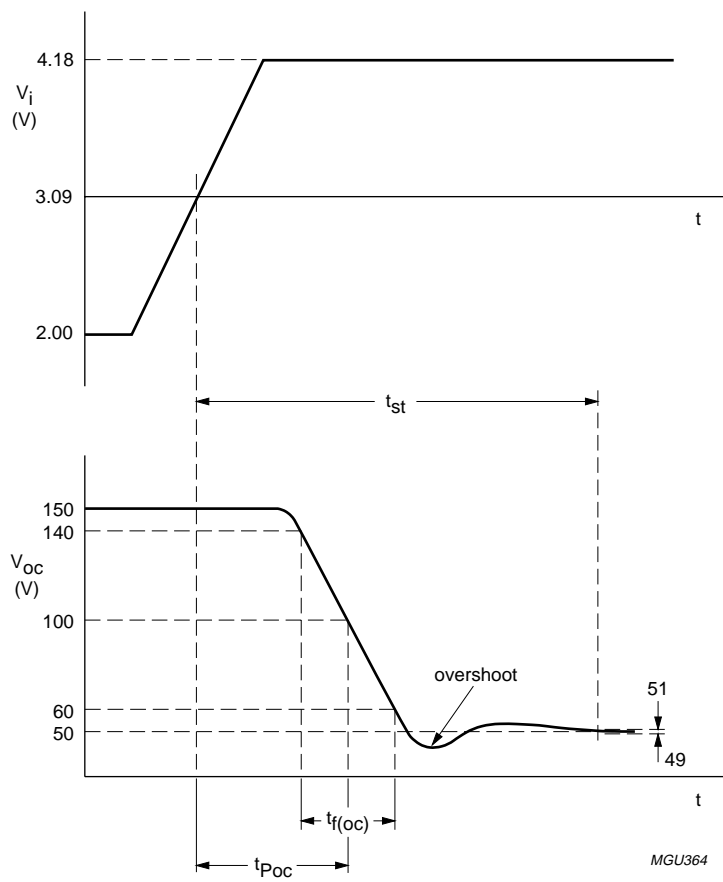


Fig.7 Output voltage (pins 7, 8 and 9) falling edge as a function of the AC input signal.

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### External flashover protection

For sufficient flashover protection it is necessary to apply an external diode and 100  $\Omega$  resistor for each channel. See Application note AN96072 of the TDA6109JF.

To limit the diode current an external 1 k $\Omega$  carbon high-voltage resistor in series with the external diode and a 2 kV spark gap are needed (for this resistor value, the CRT has to be connected to the main PCB).

$V_{DD}$  must be decoupled to GND:

1. With a capacitor >20 nF with good HF behaviour (e.g. foil); this capacitor must be placed as close as possible to pins 6 and 4, but definitely within 5 mm.
2. With a capacitor >3.3  $\mu$ F on the picture tube base print.

### Switch-off behaviour

The switch-off behaviour of the TDA6109JF is controllable. This is because the output pins of the TDA6109JF are still under control of the input pins for low power supply voltages (approximately 30 V and higher).

### Bandwidth

The addition of the flash resistor produces a decreased bandwidth and increases rise and fall times. For further information, see Application note AN96072 of the TDA6109JF.

### Dissipation

Regarding dissipation, a distinction must first be made between static dissipation (independent of frequency) and dynamic dissipation (proportional to frequency).

The static dissipation of the TDA6109JF is due to voltage supply currents and load currents in the feedback network and CRT. The static dissipation  $P_{stat}$  equals:

$$P_{stat} = V_{DD} \times I_{DD} + 3 \times V_{oc} \times I_{oc}$$

Where:

$V_{DD}$  = supply voltage

$I_{DD}$  = supply current

$V_{oc}$  = DC value of cathode voltage

$I_{oc}$  = DC value of cathode current.

The dynamic dissipation  $P_{dyn}$  equals:

$$P_{dyn} = 3 \times V_{DD} \times (C_L + C_{int}) \times f_i \times V_{oc(p-p)} \times \delta$$

Where:

$C_L$  = load capacitance

$C_{int}$  = internal load capacitance ( $\approx$ 4 pF)

$f_i$  = input frequency

$V_{oc(p-p)}$  = output voltage (peak-to-peak value)

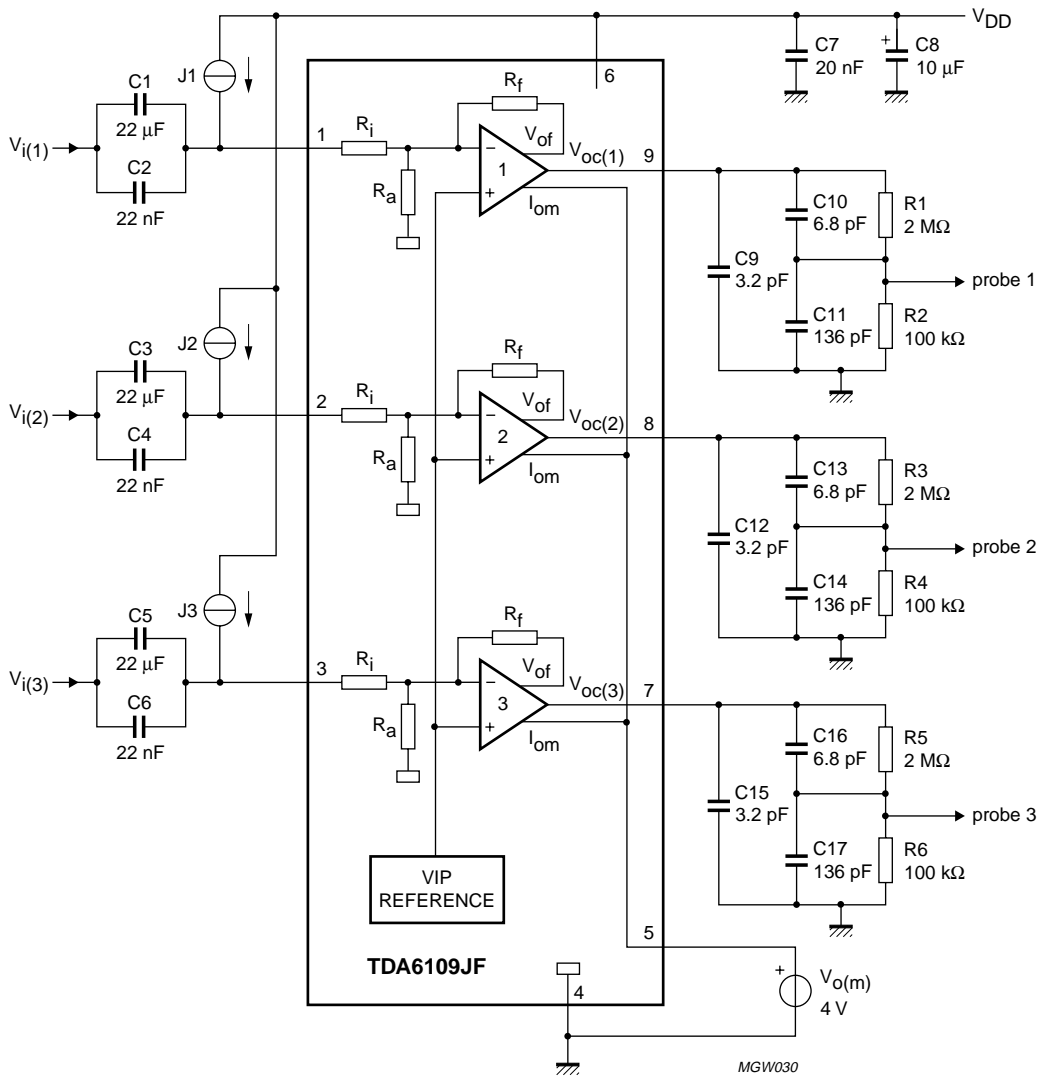
$\delta$  = non-blanking duty cycle.

The IC must be mounted on the picture tube base print to minimize the load capacitance  $C_L$ .

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## TEST AND APPLICATION INFORMATION



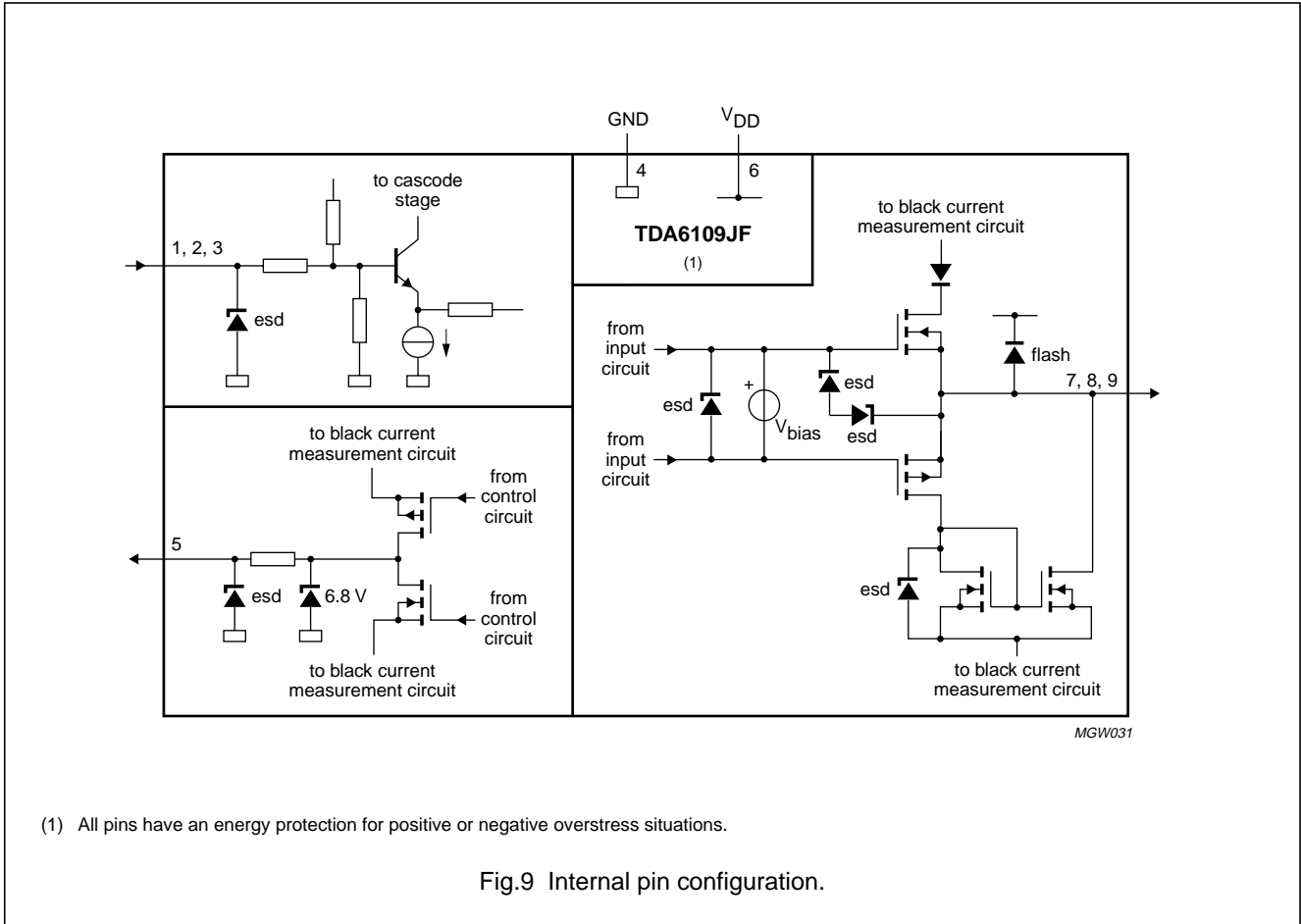
Current sources J1, J2 and J3 are to be tuned so that  $V_{oc}$  of pins 9, 8 and 7 is set to 100 V.

Fig.8 Test circuit.

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INTERNAL CIRCUITS



(1) All pins have an energy protection for positive or negative overstress situations.

Fig.9 Internal pin configuration.

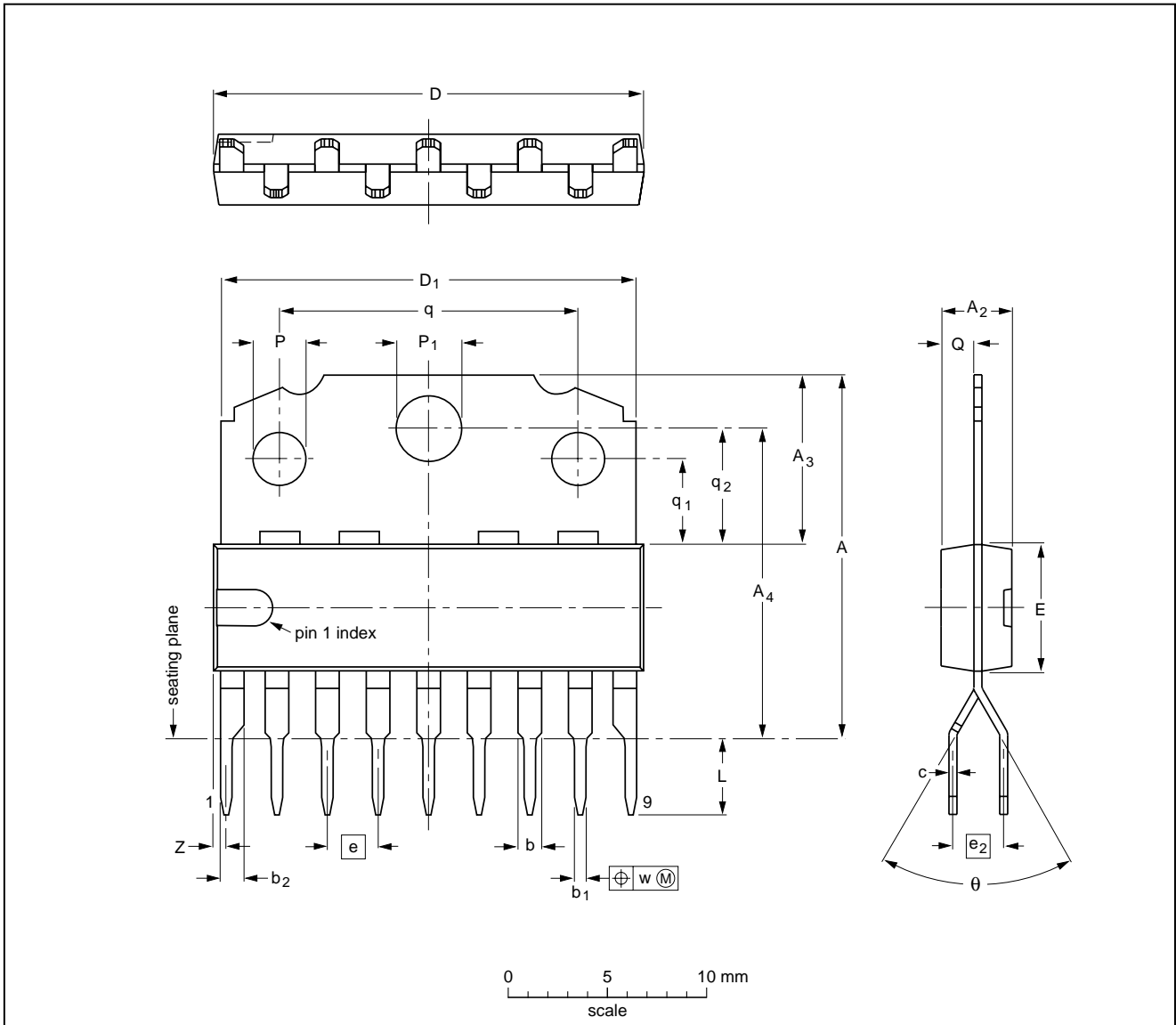
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PACKAGE OUTLINE

DBS9MPF: plastic DIL-bent-SIL medium power package with fin; 9 leads

SOT111-1



DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>2</sub> max.	A <sub>3</sub>	A <sub>4</sub>	b	b <sub>1</sub>	b <sub>2</sub>	c	D <sup>(1)</sup>	D <sub>1</sub>	E <sup>(1)</sup>	e	e <sub>2</sub>	L	P	P <sub>1</sub>	Q	q	q <sub>1</sub>	q <sub>2</sub>	w	Z <sup>(1)</sup> max.	θ
mm	18.5 17.8	3.7	8.7 8.0	15.5 15.1	1.40 1.14	0.67 0.50	1.40 1.14	0.48 0.38	21.8 21.4	21.4 20.7	6.48 6.20	2.54	2.54	3.9 3.4	2.75 2.50	3.4 3.2	1.75 1.55	15.1 14.9	4.4 4.2	5.9 5.7	0.25	1.0	65° 55°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT111-1						92-11-17 95-03-11

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**SOLDERING****Introduction to soldering through-hole mount packages**

This text gives a brief insight to wave, dip and manual soldering. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

Wave soldering is the preferred method for mounting of through-hole mount IC packages on a printed-circuit board.

**Soldering by dipping or by solder wave**

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joints for more than 5 seconds.

The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg(max)}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

**Manual soldering**

Apply the soldering iron (24 V or less) to the lead(s) of the package, either below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

**Suitability of through-hole mount IC packages for dipping and wave soldering methods**

PACKAGE	SOLDERING METHOD	
	DIPPING	WAVE
DBS, DIP, HDIP, SDIP, SIL	suitable	suitable <sup>(1)</sup>

**Note**

- For SDIP packages, the longitudinal axis must be parallel to the transport direction of the printed-circuit board.

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## DATA SHEET STATUS

DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

## Notes

1. Please consult the most recently issued data sheet before initiating or completing a design.
2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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